## Q.P. Code :09583

[ Marks:75]

Please check whether you have got the right question paper. N.B: 1. All questions are compulsory 2. Use of non-programmable scientific calculator is allowed. Useful constants:  $c=2.998 \times 10^8 \ ms^{-1}$  $N_A$ =6.023× 10<sup>23</sup>  $mol^{-1}$  $h=6.625\times 10^{-34}$  Is 1ev=1.602×  $10^{-19} J$  $1e=1.602\times 10^{-19}$  C  $R = 8.314 \text{ Jk}^{-1} \text{ mol}^{-1}$  $k=1.3811\times 10^{-23} \ JK^{-1} \ molecule^{-1}$  $m_p$ =1.673×  $10^{-27} kg$  $m_e$ =9.11× 10<sup>-31</sup> kg $\mu_{B}$ =9.274×  $10^{-24}$   $JT^{-1}$  $\mu_N = 5.051 \times 10^{-27} IT^{-1}$ Q.1 Attempt any five of the following 15 (a) How are solids classified? (b) Show that the critical radius-ratio for a triangular coordination is 0.155. (c) Distinguish between ferromagnetism and Anti-ferromagnetism. (d) Explain optical fibers. Give their importance in telecommunication. (e) Explain the terms i) Statistical weight factor 'g' ii) Occupancy number (f) Calculate number of ways to distribute i) TWO distinguishable objects in two boxes ii) TWO distinguishable objects in three boxes (g) With Jablonski diagram, explain phosphorescence (h) State and explain the principle of microscopic reversibility. 05 Q.2 a) What are vapour phase transport methods? How and where are they used? a) Describe the single crystal method for characterization of solids. 05 b) What are the factors that affect diffusion in solids? What is steady state diffusion? 05 b) What are the different types of defects in solids? What are their characteristics? How do they affect the 05 properties of solids? c) Calculate the distance between two adjacent ions of KCl crystal having F.C.C structure. 05 (Given the density of KCl =  $1.99 \times 10^3$  kg/ $m^3$  and molar mass of KCl = 74.6.) Q.3 (a) Define the terms 05 i) Valence band ii) Conduction band iii) Forbidden gap. Hence classify, The solids into conductors, semiconductors and insulators. (a) What is Nano technology? Describe in brief Three dimensional nano materials. 05 (b) With the help of Fermi-Dirac statistics. Prove that the Fermi level in Instrinsic semiconductors lies exactly at **05** the middle of the forbidden gap. OR [P.T.O]

[Time: 3 Hours]

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	(b)	What is Piezeolectricity? Describe in brief Ultrasonic echo sounding.	05
	(c)	If the ratio of $A^{3+}$ to $A^{2+}$ in a non-stoichiometric sample of ionic crystal A0 were 0.15, what fraction of cation sites would be occupied by vacancies?	05
Q.4	a)	Derive an expression for the translational partition function of gaseous molecule.	05
		OR	
	a)	Derive the relation between internal energy and partition function.	05
	b)	Derive Fermi-Dirac distribution law for Fermions using statistical considerations.  OR	05
	b)	Derive the relation between Helmholtz function and partition function.	05
	c)	The rotational constant of gaseous HCl determined from microwave spectroscopy is $10.59cm^{-1}$ . Calculate	05
		the rotational partition function of HCl at 100 K.( $\sigma=1$ ).	
Q.5	a)	Give a brief account of	05
		i) Photooxidation	
		ii) Flash photolysis.	
		OR	
	a)	Explain the terms:	
		i) Driving force	05
		ii) Flux	
		iii) Entropy production in coupled reactions	
	b)	What is fluorescence? Explain the role of intersystem crossing in fluorescence .	05
		OR	
	b)	How are electrokinetic effects explained by Onsagar's relations?	05
	c)	Explain conservation of mass in open and closed system.	05

2